From Bare Metal Powders to Colloidally Stable TCO Dispersions and Transparent Nanoporous Conducting Metal Oxide Thin Films

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Transparent conductive oxides (TCOs) are a technologically important class of materials.\(^1\) Herein we describe a facile, universal, and green ‘one-pot’ approach to produce stable dispersions comprising TCO nanoparticles (NPs) such as SnO\(_2\), In\(_2\)O\(_3\), ATO (≡SnO\(_2\):Sb), ITO (≡In\(_2\)O\(_3\):Sn), and ZTO (≡SnO\(_2\):Zn). The synthesis begins by etching the bare metal powder precursors (Sn, In, Sb, and Zn) with HCl and is completed by adding aqueous hydrogen peroxide below room temperature. No complex work-up or time-consuming purification is required, only simple filtration. Moreover, this approach avoids organic surfactants, capping ligands and/or organic solvents, metal halides like SnCl\(_4\) or SbCl\(_3\), co-ordination compounds and sol–gel precursors like Sn(OBu)\(_4\), which are commonly used in all reported syntheses of TCO NPs and which often contaminate and therefore complicate their subsequent utilization and purification.\(^2,3\) It is noteworthy that TCO nanoparticles have been synthesized in different reaction media including ionic liquids,\(^4\) polyols,\(^5\) and water.\(^6\) The herein reported TCO NPs possess diameters of 3–6 nm, are colloidally stable, can be produced on a multi-gram scale and are well-suited for spin-coating nanoporous, transparent, and conductive TCO thin films\(^7\) (see Scheme 1) with potential utility in lithium ion batteries, solar and photo-electrochemical cells, electrochromics and sensors, flat-panel displays, transparent thin-film transistors, optoelectronic devices, and photonic crystal architectures.\(^8–12\) Additionally, such TCO dispersions can potentially be ink-jet printed\(^{13}\) or electrospun into TCO nanofibers.\(^{14}\)

The synthesis begins with microscale metal powders exemplified by Sn, Zn, Sb, and In (purity 99.5 to 99.95%) which are treated first with HCl (per analysis (p.a.) 37 wt%) to dissolve the native metal oxide shell, followed by a very slow and dropwise addition of aqueous H\(_2\)O\(_2\) (p.a. 30 wt%) yielding in the complete oxidative dissolution of the etched metal powders and the formation of colloidally stable TCO NP dispersions (see Figure 1a–c).

Due to the highly exothermic nature of our reaction, the synthetic procedure is limited to the preparation of several grams of TCO dispersions on the lab-scale; industrial scalability on a multi-kilogram or multi-ton approach will be not possible with the approach described here. This one-pot TCO synthesis is envisioned as a controlled oxidative dissolution of micrometer-scale metal powder precursors to create metal oxide embryonic seeds which accrete metal oxide solution phase species and grow to form the product metal oxide nanoparticles.\(^{13,19,25}\)

A detailed study of the synthesis is given for In\(_2\)O\(_3\) and its controlled Sn doping levels (e.g., ≈5, 10, 15 and 20 wt%) of ITO (≡In\(_2\)O\(_3\):Sn). Additionally, and as a proof-of-concept for this method, the formation of SnO\(_2\) and ATO (≡SnO\(_2\):Sb) and ZTO (≡SnO\(_2\):Zn) are shown (for details see the Supporting Information (SI)). The Sn and Sb doping levels in ITO (≡In\(_2\)O\(_3\):Sn) and ATO (≡SnO\(_2\):Sb) were estimated from powder X-ray diffraction (PXRD) Rietveld analysis with comparisons to published data on lattice parameters (for details see Table S1 and S2 in the SI).\(^{15–17}\) The increase of the Sn concentration in In\(_2\)O\(_3\) was confirmed by X-ray photoelectron spectroscopy (XPS) and through conductivity measurements at different doping levels (see SI Figures S26–S29 and Table S6). Furthermore, XPS analysis showed that HCl (37 wt%) is crucial for the complete dissolution of the native metal oxide shell of the employed bare metal precursor (see Figure S27 in the SI). After the complete dissolution of the native metal oxide layer, the respective metal powder(s) forms compact metal agglomerates (see the Experimental Section in the SI). Oxidative dissolution of the metal agglomerate occurs only if the etching process with HCl was applied beforehand (see also Figure S28, SI). The aqueous TCO synthesizes are carried at a low temperature using an ice bath with vigorous stirring,
SnO$_2$ and In$_2$O$_3$ as well as the doped ITO, ATO, and ZTO of crystalline SnO$_2$ NPs with selected area, marked II, fast Fourier transform (FFT) and inverse FFT analyses of the image.

Table colloidal stable TCO dispersions and nanoporous TCO thin films.

Figure 1. Transformation of bare metal powder precursors with $M = $ Sn, In, Sb and Zn to colloidal and stable TCO dispersions and nanoporous TCO thin films.

Scheme 1. Transformation of bare metal powder precursors with $M = $ Sn, In, Sb and Zn to colloidal stable TCO dispersions and nanoporous TCO thin films.

Under very acidic conditions ($pH = -1$), the formation of metal halides is unfavorable due to the high oxidation potential of the $\text{H}_2\text{O}_2/\text{H}_2\text{O}$ redox couple ($E^\ddagger = 1.763$ V).[^11] It is important to note that crystalline TCO NP dispersions are obtained under conditions between 0 and 25 $^\circ\text{C}$ by simple stirring (see Figures S3–S7 in the SI). Further washing, extraction, or separation and purification steps are not required. Mostly high temperatures—200–300 $^\circ\text{C}$ in solvothermal reactions[^9]—are required to form crystalline SnO$_2$, In$_2$O$_3$, ATO ($=$SnO$_2$:Sb), ITO ($=$In$_2$O$_3$:Sn), and ZTO ($=$SnO$_2$:Zn) NP dispersions (see Table 1).

PXRD confirmed the phase purity of the synthesised SnO$_2$ and In$_2$O$_3$ as well as the doped ITO, ATO, and ZTO dispersions, where no extraneous peaks could be detected (see SI, Figures S1–S2). Profile fitting procedures (Pawley decomposition and Rietveld refinement) were used for lattice parameter refinement of the pure and doped TCOs. It was found that Sb-doping in SnO$_2$ enlarges the lattice, while Sn-doping in In$_2$O$_3$ does not follow Vegard’s Law at the highest levels of Sn doping ($>$10 wt%; for details see SI, Tables S1 and S2). This behavior is in full agreement with published data for Sn$_{1-x}$In$_x$O$_2$ composition tuning.[^15–17]

TCO NP sizes of dried dispersions were obtained from PXRD measurements via full-profile Rietveld refinement.[^21]

scanning transmission electron microscopy (STEM), and high-resolution transmission electron microscopy (HR-TEM) techniques, as well as dynamic light scattering (DLS), finding good agreement among these methods, as shown in Table 1. The HR-TEM and STEM images of In$_2$O$_3$, ZTO, and SnO$_2$ dispersions are provided in Figure 1a–c, demonstrating the spherical morphology of crystalline TCO NPs. The observed lattice fringes in the TEM image of SnO$_2$ NPs and further analysis by the fast Fourier transform (FFT) and its inverse FFT of a selected area, marked II, in the TEM image show crystalline domains of the NPs to be consistent with the lattice parameters obtained from the PXRD results (Figure 1c). The colloidal stability of the NPs most likely originates from the presence of electrical double-layer repulsive forces between charged NPs as described by DLVO theory[^22–23] while surface charges can be traced to the ionization of surface groups or adsorption of charged species present in the reaction medium (see Scheme 2 and Figure 8 in the SI). From zeta potential measurements, the TCO NPs are found to be positively charged (e.g., $\zeta = 41.7 \pm 1$ mV for SnO$_2$, $26.1 \pm 1.7$ mV for ATO ($=$SnO$_2$:Sb) and $23.5 \pm 1.4$ mV for ZTO) under acidic conditions (at $pH = 1.3$–1.7) and diluted (1:30),[^24,25] which is consistent with a protonated surface oxide and/or hydroxide groups (see SI, Table S5). These stabilizing surface species include hydroxonium groups ($\text{H}_3\text{O}_+^+$), water ($\text{OH}_2^-$), protonated oxygens ($\text{OH}^-$), as well as protonated superoxo/peroxo groups ($\text{O}^2\text{O}_2^+$) and chloride (Cl$^-$) all envisioned to be present within the inner Stern Layer and diffuse outer counteranion layer.[^26,27] The Raman spectra of the as-synthesized and oven-dried dispersions display intense peaks due to surface species that can be mostly eliminated upon calcination. The spectra of the calcined TCO NPs and ATO NPs are similar to bulk counterparts of TCOs (see SI, Figures S19–S23 and Table S4). The colloidal stability most likely results from the presence of chloride counteranions (Cl$^-$), evidence for which has been found in dried samples through EDX elemental mapping, as well as from XPS measurements and M–Cl stretching and deformation modes in the Raman spectra; for details see SI (Figures S8, S20–23 and S28).

UV–vis–NIR absorption spectra and SEM images of TCO NP films that are spin-coated and then annealed at 450 $^\circ\text{C}$ for 15–20 min in air, on quartz and/or silicon substrates collectively show the optical quality, structural integrity, and porosity of the films (see SI, Figures S9–S18). The UV–vis–NIR spectra of different metal oxide thin films (shown in the SI, Figures S14–S18) display characteristic absorption edges that are slightly blue-shifted from their respective bulk metal oxides. The observed blue-shifts are attributed to the nanoscale size of the NP dispersions seen in DLS, STEM, and HR-TEM measurements (further details of the UV–vis–NIR spectra for details see SI (Figures S8, S20–23 and S28).
data can be found in the SI, Table S3). Some TCO NP films were also prepared on resistive glass (Corning 1737) in order to measure their sheet resistance using a four point probe station (Four Dimensions, inc. Model 101C). The sheet resistance for films prepared from SnO$_2$, In$_2$O$_3$, ATO and ITO NPs annealed at either 450 °C or 650 °C for 15–20 min are shown in Figure 2a. The sheet resistance of the TCO NP films after annealing in air at 650 °C range from as high as 8.8 × 10$^5$ Ω/□ for the SnO$_2$ NP film to as low as 4.8 × 10$^5$ Ω/□ for the ITO NP film. Higher annealing temperatures lead to a higher densification and less porosity and grain boundary effects between the adjacent/sintered TCO nanoparticles, therefore resulting in a higher mobility and percolation of electrons throughout the films. We also measured the sheet resistance of the series of films prepared from In$_2$O$_3$ with controlled Sn doping levels (e.g., ~5, 10, 15, and 20 wt%) and the results are shown in Figure 2b. A minimum sheet resistance of 1.9 × 10$^5$ Ω/□ was measured for the sample doped with 10 wt% Sn. This corresponds to a resistivity of ~0.02 Ω cm which is consistent with values reported previously in the literature.[26] The resistivity of all samples presented in Figure 2a,b are listed in SI, Tables S5 and S6.

In conclusion, we have presented a simple, green, robust, widely applicable and cost-effective ‘one-pot’ multi-gram synthesis to aqueous dispersions of colloidaly stable 3–6 nm TCO NPs, using bare metal powder precursors. Their utilization for making TCO high surface area nanoporous films has also been demonstrated, which provides opportunities for their usage in a wide range of processes and devices.

### Experimental Section

Sn, In, Sb, Zn metal powders (≤10 μm, mesh 200 and mesh 325, purity 99.9–99.9995% metal basis), H$_2$O$_2$ (30% p.a.) were obtained from Sigma-Aldrich, Alfa Aesar and Caledon Laboratory Chemicals, respectively. Silicon wafers (University Wafer, Lot: 1-800-216-8346) were obtained from Wafer World.

SnO$_2$, In$_2$O$_3$, ITO (≡In$_2$O$_3$:Sn), ATO (≡SnO$_2$:Sb) and ZTO (≡SnO$_2$:Zn) were synthesized by dissolution of 1–3 g of the elemental metal powder of Sn, In, Sb or Zn (ASP ≤ 10 μm, mesh 200 and 325), dispersed in 5 mL of deionised H$_2$O (0.056 μS/cm), followed by the addition of 8 mL HCl (37 wt%) at 0 °C and, after ~20 to (max.) 30 min, the slow and dropwise addition of 10–25 mL H$_2$O$_2$ (30% p.a.) under nitrogen while cooling the reaction mixture in an ice bath due to the exothermic nature of the dissolution/oxidation process, followed by further stirring of the mixture for 12–18 h under air/nitrogen. Addition of HCl causes the complete dissolution of the native metal oxide layer of the respective metal powder(s) and causes the metal powder(s) to agglomerate into a compact metal piece. This synthetic procedure, for each of the metal oxide dispersions from their respective bare metal precursors, has been reproduced at least 3–5 times.

**CAUTION:** Very exothermic reaction! Addition of the HCl and H$_2$O$_2$ has to be done slowly and dropwise, with continuous ice-bath cooling during the addition and reaction/dissolution processes, in a well ventilated hood. Protective glasses, gloves and a lab coat must be worn at all times during this synthetic procedure, and it is recommended that the procedure should be carried out only by a well-trained scientist! The 250 or 500 mL 2-neck round-bottom

### Scheme 2

Illustration of the double-layer surface charge stabilization responsible for the colloidal stability of TCO NPs with a protonated inner Stern Layer and a diffuse outer chloride counteranion layer.[26,27]

### Table 1. Characterization of the Size of TCO NPs by STEM, HR-TEM, and DLS.

<table>
<thead>
<tr>
<th>Metal</th>
<th>TCOs</th>
<th>STEM [nm]$^a$</th>
<th>HR-TEM [nm]$^b$</th>
<th>DLS [nm]$^c$</th>
</tr>
</thead>
<tbody>
<tr>
<td>Sn</td>
<td>SnO$_2$</td>
<td>3–6</td>
<td>3.7 ± 0.4</td>
<td>7.7 ± 1.6</td>
</tr>
<tr>
<td>In</td>
<td>In$_2$O$_3$</td>
<td>2–6</td>
<td>3.1 ± 0.3</td>
<td>6.3 ± 1.3</td>
</tr>
<tr>
<td>Sn + Sb</td>
<td>ATO</td>
<td>6–14</td>
<td>7.8 ± 1.8</td>
<td>17.5 ± 2.1</td>
</tr>
<tr>
<td>In + Sn</td>
<td>ITO</td>
<td>2–5</td>
<td>3.2 ± 0.3</td>
<td>6.5 ± 1.4</td>
</tr>
<tr>
<td>Zn + Sn</td>
<td>ZTO</td>
<td>3–6</td>
<td>3.5 ± 0.3</td>
<td>7.5 ± 1.5</td>
</tr>
</tbody>
</table>

$^a$Metal powders Sn ≤ 10 μm, Sb mesh 325, Zn mesh 200, In mesh 325; $^b$STEM, HR-TEM 300 kV; $^c$Nano-DLS at λ = 633 nm.
flask reaction vessel should be never closed too tightly. Final stirring of the reaction mixture at room temperature overnight leads, for example, to a light-yellow to yellow In₂O₃ dispersion, a trans-
parent–milky SnO₂ dispersion, or a blue-gray ATO (≡SnO₂:Sb) dispersion. The dispersions were stored in plastic bottles at 4 °C and the bottle caps additionally had holes in them. Dopants were introduced by weighing metal powders according to their molar ratios to obtain the desired TCO NP products.

Supporting Information

Supporting Information is available from the Wiley Online Library or from the author.

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